

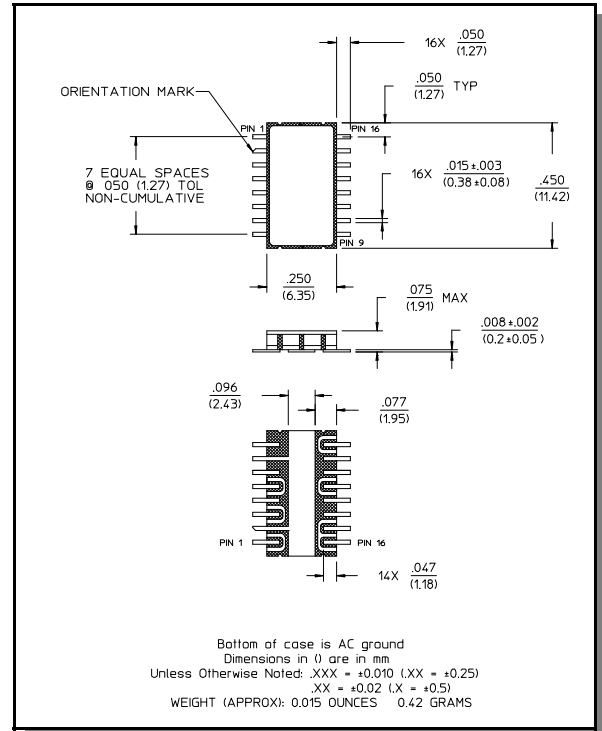
Features

- Integral TTL Driver
- Low DC Power Consumption
- Surface Mount Package
- Low Cost/High Performance
- 50 Ohm Nominal Impedance

Description

M/A-COM's SW10-0313 is a GaAs FET SPDT absorptive switch with integral silicon ASIC driver. Packaged in a 16-lead ceramic surface mount package, this device offers excellent performance and repeatability from DC to 3 GHz while maintaining low power consumption. The SW10-0313 is ideally suited for use where fast speed, low power consumption and broadband applications are required.

CR-9



Electrical Specifications^{1,2} T_A = +25°C

Parameter	Test Conditions	Frequency	Units	Min	Typ	Max
Insertion Loss	—	DC - 3000 MHz	dB	—	0.8	1.2
		DC - 2000 MHz	dB	—	0.7	1.1
		DC - 1000 MHz	dB	—	0.7	0.9
		DC - 500 MHz	dB	—	0.6	0.8
VSWR	—	DC - 3000 MHz	Ratio	—	1.2:1	1.4:1
		DC - 2000 MHz	Ratio	—	1.2:1	1.35:1
		DC - 1000 MHz	Ratio	—	1.2:1	1.35:1
		DC - 500 MHz	Ratio	—	1.1:1	1.3:1
Isolation	—	DC - 3000 MHz	dB	35	40	—
		DC - 2000 MHz	dB	45	50	—
		DC - 1000 MHz	dB	45	50	—
		DC - 500 MHz	dB	50	55	—
Trise, Tfall	10% to 90%	—	ns	—	50	—
Ton, Toff	1.3V CTL to 90% / 10%	—	ns	—	150	—
Transients	In-Band	—	mV	—	50	—
1 dB Compression	Input Power	0.05 GHz	dBm	—	+25	—
		0.5 GHz to 3 GHz	dBm	—	+30	—
IP2	Two-Tone Input Power up to +5 dBm	0.05 GHz	dBm	—	+60	—
		0.5 GHz to 3 GHz	dBm	—	+65	—
IP3	Two-Tone Input Power up to +5 dBm	0.05 GHz	dBm	—	+40	—
		0.5 GHz to 3 GHz	dBm	—	+46	—
Vin Low	0V to 0.8V	—	µA	—	—	1
Vin High	2.0V to 5.0V	—	µA	—	—	1

1. All specifications apply when operated with bias voltages of +5V for Vcc and -5V for Vee.
 2. When DC blocks are used, a 10K ohm return to GND is required on the RFC port.

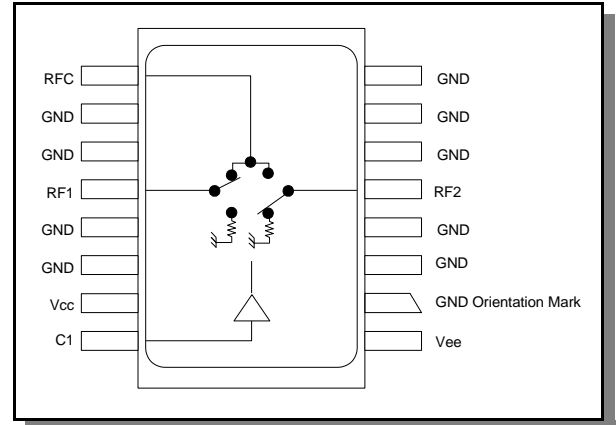
Electrical Specifications: $T_A = +25^\circ\text{C}$

Parameter	Test Conditions	Frequency	Units	Min	Typ	Max
Vcc	+5.0V \pm 10%	—	mA	—	—	1
Vee	-5.0V to -8.0V	—	mA	—	—	1

Pin Configuration

Pin No.	Function	Pin No.	Function
1	Vee	9	RFC
2	GND	10	GND
3	GND	11	GND
4	GND	12	RF1
5	RF2	13	GND
6	GND	14	GND
7	GND	15	Vcc
8	GND	16	C1

Pin Configuration (Top View)



Absolute Maximum Ratings ³

Parameter	Absolute Maximum
Max Input Power 50 MHz 500 - 2000 MHz	+27 dBm +34 dBm
Supply Voltages Vcc Vee	+5.5V -8.5V
Control Voltage ⁴	-0.5V, to Vcc +0.5V
Operating Temperature	-40°C to +125°C
Storage Temperature	-65°C to +150°C

Truth Table

C1	Condition of Switch	
	RF Common to Each RF Port	
	RF1	RF2
LO	On	Off
HIGH	Off	On

3. Operation of this device above any one of these parameters may cause permanent damage.
4. Standard CMOS TTL interface, latch-up will occur if logic signal is applied prior to power supply.

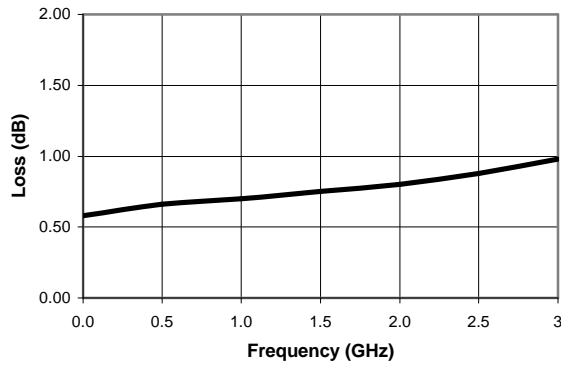
Specifications subject to change without notice.

■ **North America:** Tel. (800) 366-2266
 ■ **Asia/Pacific:** Tel.+81-44-844-8296, Fax +81-44-844-8298
 ■ **Europe:** Tel. +44 (1344) 869 595, Fax+44 (1344) 300 020

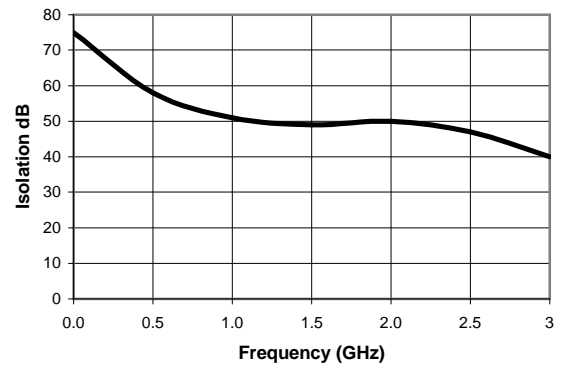
Visit www.macom.com for additional data sheets and product information.

Typical Performance Curves

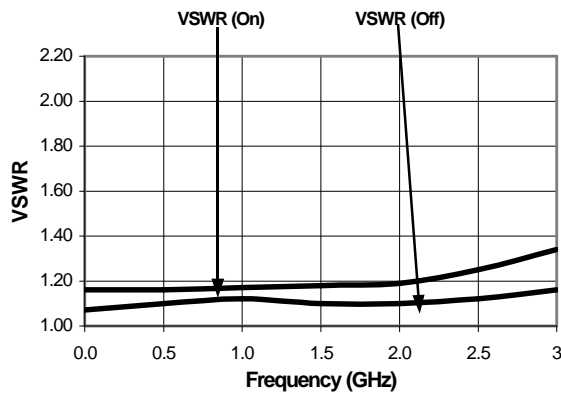
Insertion Loss vs. Frequency



Isolation vs. Frequency



VSWR vs. Frequency



Ordering Information

Part Number	Package
SW10-0313	CR-9

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